## Optocoupler, Photodarlington Output, AC Input, High Gain (Single, Dual Channel)

## Features

- AC or Polarity Insensitive Inputs
- Built-in Reverse Polarity Input Protection
- Industry Standard DIP Package


## Agency Approvals

- UL File \#E52744 System Code H or J
- CSA 93751
- BSI IEC60950 IEC60965
- DIN EN 60747-5-2(VDE0884)

DIN EN 60747-5-5 pending
Available with Option 1

## Applications

Designed for applications requiring detection or monitoring of AC signals.

## Description

The IL755/ ILD755 are bidirectional input optically coupled isolators. They consist of two Gallium Arsenide infrared emitting diodes coupled to a silicon NPN photodarlington per channel.


The IL755 is single channel Darlington optocouplers. The ILD755 has two isolated channels in a single DIP package.

Order Information

| Part | Remarks |
| :--- | :--- |
| IL755-1 | CTR $>750$ \%, DIP-8 |
| IL755-2 | CTR $>1000$ \%, DIP-8 |
| ILD755-1 | CTR $>750 \%$, DIP-8 |
| ILD755-2 | CTR $>1000 \%$, DIP-8 |
| IL755-1-X007 | CTR $>750 \%$, SMD-8 (option 7) |

For additional information on the available options refer to Option Information.

## Absolute Maximum Ratings

$\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified
Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

Input

| Parameter | Test condition | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Forward continuous current |  | $\mathrm{I}_{\mathrm{F}}$ | 60 | mA |
| Power dissipation |  | $\mathrm{P}_{\text {diss }}$ | 100 | mW |
| Derate linearly from $25^{\circ} \mathrm{C}$ |  |  | 1.33 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |

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Output

| Parameter | Test condition | Part | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-emitter breakdown voltage |  |  | BV ${ }_{\text {CEO }}$ | 60 | V |
| Collector-base breakdown voltage |  |  | $\mathrm{BV}_{\mathrm{CBO}}$ | 60 | V |
| Power dissipation |  | IL755-1 | $\mathrm{P}_{\text {diss }}$ | 200 | mW |
|  |  | IL755-2 | $\mathrm{P}_{\text {diss }}$ | 200 | mW |
|  |  | ILD755-1 | $\mathrm{P}_{\text {diss }}$ | 150 | mW |
|  |  | ILD755-2 | $\mathrm{P}_{\text {diss }}$ | 150 | mW |
| Derate linearly from $25{ }^{\circ} \mathrm{C}$ |  | IL755-1 |  | 2.6 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  |  | IL755-2 |  | 2.6 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  |  | ILD755-1 |  | 2.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  |  | ILD755-2 |  | 2.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |

Coupler

| Parameter | Test condition | Part | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Isolation test voltage (PK) | $\mathrm{t}=1.0 \mathrm{sec}$. |  | $\mathrm{V}_{\text {ISO }}$ | 7500/5300 | $\mathrm{VAC}_{\text {PK }} / \mathrm{V}_{\mathrm{RMS}}$ |
| Total power dissipation (LED plus detector) |  | IL755-1 | $\mathrm{P}_{\text {tot }}$ | 250 | mW |
|  |  | IL755-2 | $\mathrm{P}_{\text {tot }}$ | 250 | mW |
|  |  | ILD755-1 | $\mathrm{P}_{\text {tot }}$ | 400 | mW |
|  |  | ILD755-2 | $\mathrm{P}_{\text {tot }}$ | 400 | mW |
| Derate linearly from $25^{\circ} \mathrm{C}$ |  | IL755-1 |  | 3.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  |  | IL755-2 |  | 3.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  |  | ILD755-1 |  | 3.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  |  | ILD755-2 |  | 3.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| Creepage |  |  |  | $\geq 7$ | mm |
| Clearance |  |  |  | $\geq 7$ | mm |
| Storage temperature |  |  | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Operating temperature |  |  | $\mathrm{T}_{\text {amb }}$ | -55 to +100 | ${ }^{\circ} \mathrm{C}$ |
| Lead soldering time at $260{ }^{\circ} \mathrm{C}$ |  |  |  | 10 | sec. |

## Electrical Characteristics

$\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified
Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

## Input

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Forward voltage | $\mathrm{I}_{\mathrm{F}}= \pm 10 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{F}}$ |  | 1.2 | 1.5 | V |

## Output

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| Collector-emitter breakdown voltage | $\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{~mA}$ | $\mathrm{BV}_{\mathrm{CEO}}$ | 60 | 75 |  | V |
| Collector-base breakdown voltage | $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A}$ | $\mathrm{BV}_{\mathrm{CBO}}$ | 60 | 90 |  | V |
| Collector-emitter leakage current | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{CEO}}$ |  | 10 | 100 | nA |

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| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-emitter saturation voltage | $\mathrm{I}_{\mathrm{F}}= \pm 10 \mathrm{~mA}$, <br> $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{CE} \text { (sat) }}$ |  |  | 1.0 | V |

## Current Transfer Ratio

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Current Transfer <br> Ratio | $\mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}= \pm 2.0 \mathrm{~mA}$ | IL755-1 | CTR | 750 |  |  |  |
|  |  |  |  |  |  |  |  |
|  |  | ILD755-1 | CTR | 750 |  |  | $\%$ |
|  | $\mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}= \pm 1.0 \mathrm{~mA}$ | IL755-2 | CTR | 1000 |  |  | $\%$ |
|  |  | ILD755-2 | CTR | 1000 |  |  |  |

## Switching Characteristics

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Rise time | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | IL755-1 | $t_{r}$ |  | 50 |  | $\mu \mathrm{s}$ |
|  |  | ILD755-1 | $\mathrm{t}_{\mathrm{r}}$ |  | 50 |  | $\mu \mathrm{s}$ |
| Fall time | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | IL755-1 | $t_{\text {f }}$ |  | 50 |  | $\mu \mathrm{s}$ |
|  |  | ILD755-1 | $\mathrm{t}_{\mathrm{f}}$ |  | 50 |  | $\mu \mathrm{s}$ |
| Rise time | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=1.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | IL755-2 | $\mathrm{t}_{\mathrm{r}}$ |  | 70 |  | $\mu \mathrm{s}$ |
|  |  | ILD755-2 | $\mathrm{t}_{\mathrm{r}}$ |  | 70 |  | $\mu \mathrm{s}$ |
| Fall time | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=1.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | IL755-2 | $\mathrm{t}_{\mathrm{f}}$ |  | 70 |  | $\mu \mathrm{s}$ |
|  |  | ILD755-2 | $\mathrm{t}_{\mathrm{f}}$ |  | 70 |  | $\mu \mathrm{s}$ |

Typical Characteristics ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ unless otherwise specified)


Fig. 1 LED Forward Current vs.Forward Voltage

iir 75.02

Fig. 2 Normalized Non-saturated and Saturated CTR CE vs. LED Current

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Fig. 3 Normalized Non-saturated and Saturated CTR CE vs. LED Current

iir55_04
Fig. 4 Normalized Non-Saturated and Saturated ICE vs. LED Current

iil755_05

Fig. 5 Normalized Non-Saturated and Saturated Collector-Emitter Current vs. LED Current

${ }^{11755} .06$
Fig. 6 Non-Saturated and Saturated HFE vs. Base Current

${ }^{11755} 07$

Fig. 7 Low to High Propagation Delay vs. Collector Load Resistance and LED Current


Fig. 8 High to low Propagation Delay vs. Collector Load Resistance and LED Current

ii1755_09

Fig. 9 Switching Waveform

## Package Dimensions in Inches (mm)



Fig. 10 Normalized Non-Saturated and Saturated CTR $_{\text {CE }}$ vs. LED Current

ii1755_10

## IL755/ ILD755

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## Package Dimensions in Inches (mm)



18447

## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.
It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).
The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.
Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.
3. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
4. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
5. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor $\mathbf{G m b H}$ can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 672423

